74HC163-Q100; 74HCT163-Q100

Presettable synchronous 4-bit binary counter; synchronous reset

Rev. 2 — 12 October 2018

Product data sheet

1. General description

The 74HC163-Q100; 74HCT163-Q100 is a synchronous presettable binary counter with an internal look-head carry. Synchronous operation is provided by having all flip-flops clocked simultaneously on the positive-going edge of the clock (CP). The outputs (Q0 to Q3) of the counters may be preset to a HIGH or LOW. A LOW at the parallel enable input (\overline{PE}) disables the counting action. It causes the data at the data inputs (D0 to D3) to be loaded into the counter on the positive-going edge of the clock. Preset takes place regardless of the levels at count enable inputs (CEP and CET). A LOW at the master reset input (\overline{MR}) sets Q0 to Q3 LOW after the next positive-going transition on the clock input (CP). This action occurs regardless of the levels at input pins \overline{PE} , CET and CEP. This synchronous reset feature enables the designer to modify the maximum count with only one external NAND gate. The look-ahead carry simplifies serial cascading of the counters. Both CEP and CET must be HIGH to count. The CET input is fed forward to enable the terminal count output (TC). The TC output thus enabled will produce a HIGH output pulse of a duration approximately equal to a HIGH output of Q0. This pulse can be used to enable the next cascaded stage. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} .

The CP to TC propagation delay and CEP to CP set-up time determine the maximum clock frequency for the cascaded counters according to the following formula:

$$f_{\text{max}} = \frac{1}{t_{P(\text{max})}(\text{CPtoTC}) + t_{\text{SU}}(\text{CEPtoCP})}$$

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Complies with JEDEC standard no. 7A
- Input levels:
 - For 74HC163: CMOS level
 - For 74HCT163: TTL level
- Synchronous counting and loading
- 2 count enable inputs for n-bit cascading
- Synchronous reset
- Positive-edge triggered clock
- ESD protection:
 - MIL-STD-883, method 3015 exceeds 2000 V
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pF; R = 0 Ω)
- Multiple package options

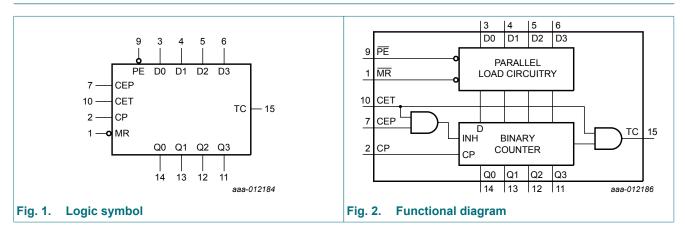


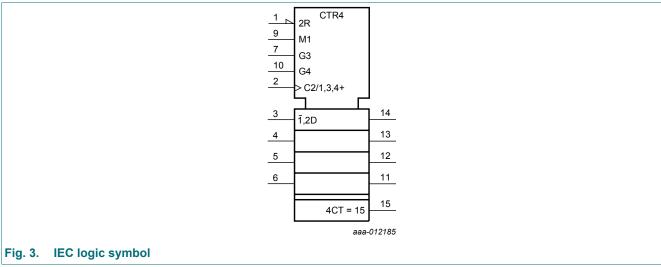
3. Ordering information

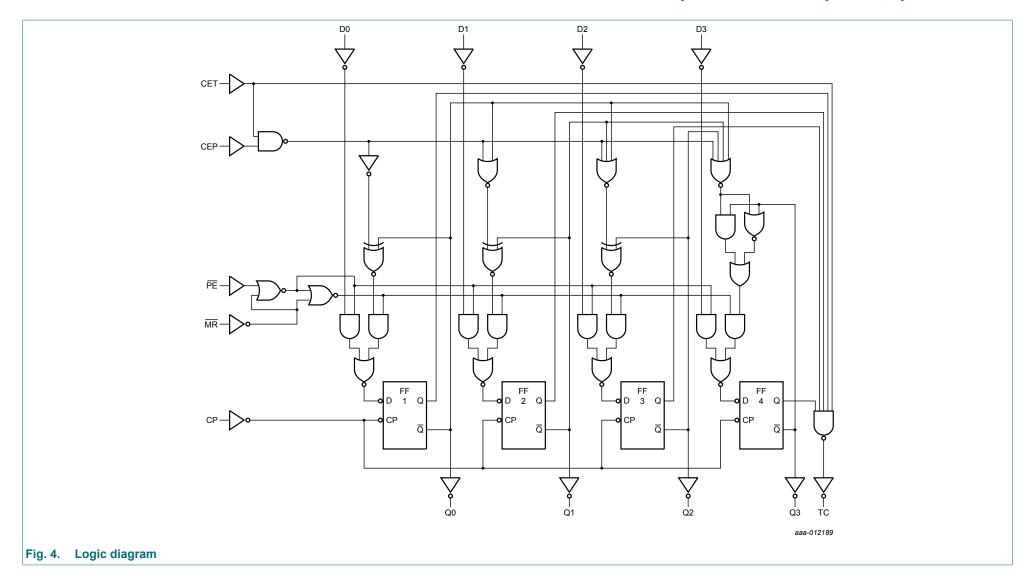
Table 1. Ordering information

Type number	Package	Package								
	Temperature range	Name	Description	Version						
74HC163D-Q100	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads;	SOT109-1						
74HCT163D-Q100			body width 3.9 mm							
74HC163PW-Q100	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package;	SOT403-1						
74HCT163PW-Q100			16 leads; body width 4.4 mm							

4. Functional diagram

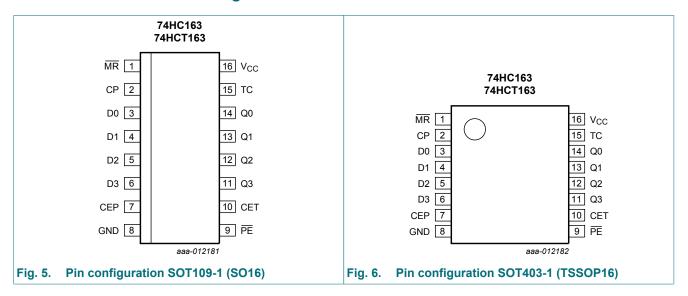






5. Pinning information

5.1. Pinning



5.2. Pin description

Table 2. Pin description

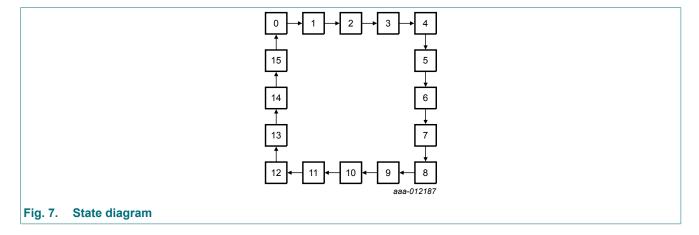
Symbol	Pin	Description
MR	1	synchronous master reset (active LOW)
СР	2	clock input (LOW-to-HIGH, edge triggered)
D0, D1, D2, D3	3, 4, 5, 6	data input
CEP	7	count enable input
GND	8	ground (0 V)
PE	9	parallel enable input (active LOW)
CET	10	count enable carry input
Q0, Q1, Q2, Q3	14, 13, 12, 11	flip-flop output
TC	15	terminal count output
V _{CC}	16	supply voltage

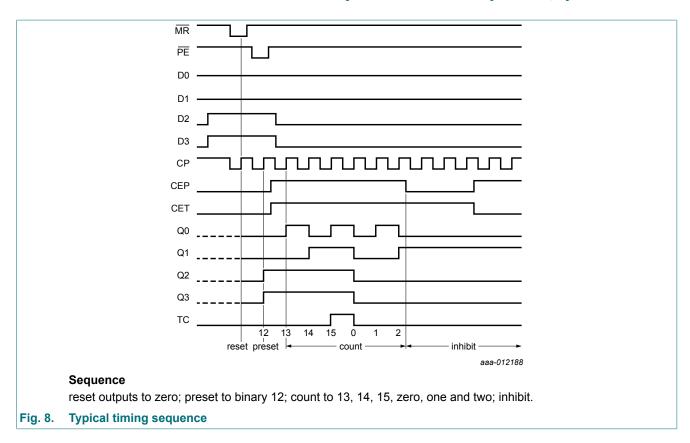
6. Functional description

Table 3. Function table[1]

Operating mode	Inputs	Inputs							
	MR	СР	CEP	CET	PE	Dn	Qn	TC	
Reset (clear)	I	1	Х	Х	Х	Х	L	L	
Parallel load	h	1	Х	Х	I	I	L	L	
	h	1	Х	Х	I	h	Н	L	
Count	h	1	h	h	h	Х	count		
Hold (do nothing)	h	Х	I	Х	h	Х	qn	L	
	h	Х	Х	I	h	Х	qn	L	

- [1] The TC output is HIGH when CET is HIGH and the counter is at terminal count (HHHH);
 - H = HIGH voltage level;
 - h = HIGH voltage level one set-up time prior to the LOW-to-HIGH CP transition;
 - L = LOW voltage level;
 - I = LOW voltage level one set-up time prior to the LOW-to-HIGH CP transition;
 - q = lower case letters indicate the state of the referenced output one set-up time prior to the LOW-to-HIGH CP transition;
 - X = don't care;
 - \uparrow = LOW-to-HIGH clock transition.





7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7.0	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	-	±20	mA
I _{OK}	output clamping current	V_{O} < -0.5 V or V_{O} > V_{CC} + 0.5 V	-	±20	mA
Io	output current	$V_{O} = -0.5 \text{ V to } V_{CC} + 0.5 \text{ V}$	-	±25	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	SO16 package	1] -	500	mW
		TSSOP16 package	1] -	500	mW

^[1] For SO16 packages: above 70 $^{\circ}$ C the value of P_{tot} derates linearly at 8 mW/K. For TSSOP16 packages: above 60 $^{\circ}$ C the value of P_{tot} derates linearly at 5.5 mW/K.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions	74HC163-Q100			74H	CT163-0	2100	Unit	
			Min	Тур	Max	Min	Тур	Max		
V _{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V	
VI	input voltage		0	-	V _{CC}	0	-	V _{CC}	V	
Vo	output voltage		0	-	V _{CC}	0	-	V _{CC}	V	
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C	
Δt/ΔV	input transition rise and fall rate	V _{CC} = 2.0 V	-	-	625	-	-	-	ns/V	
		V _{CC} = 4.5 V	-	1.67	139	-	1.67	139	ns/V	
		V _{CC} = 6.0 V	-	-	83	-	-	-	ns/V	

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C to	o +85 °C	-40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC163	3-Q100									
V _{IH}	HIGH-level	V _{CC} = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	V _{CC} = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V
V_{IL}	LOW-level	V _{CC} = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
	input voltage	V _{CC} = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
	V _{CC} = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V	
V _{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL}								
	output voltage	I _O = -20 μA; V _{CC} = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		I _O = -20 μA; V _{CC} = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		I _O = -20 μA; V _{CC} = 6.0 V	5.9	6.0	-	5.9	-	5.9	-	V
		I _O = -4.0; V _{CC} = 4.5 V	3.98	4.32	-	3.84	-	3.7	-	V
		I _O = -5.2; V _{CC} = 6.0 V	5.48	5.81	-	5.34	-	5.2	-	V
V_{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL}								
	output voltage	I_{O} = 20 μ A; V_{CC} = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 20 μA; V _{CC} = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I_{O} = 20 μ A; V_{CC} = 6.0 V	-	0	0.1	-	0.1	-	0.1	V
		I _O = 4.0 mA; V _{CC} = 4.5 V	-	0.15	0.26	-	0.33	-	0.4	V
		I _O = 5.2 mA; V _{CC} = 6.0 V	-	0.16	0.26	-	0.33	-	0.4	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0 \text{ V}$	-	-	8.0	-	80.0	-	160.0	μΑ
Cı	input capacitance		-	3.5	-	-	-	-	-	pF

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	1
74HCT1	63-Q100			'			-			
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	1.2	8.0	-	0.8	-	8.0	V
V _{OH} HIGH-level		$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 V$								
	output voltage	I _O = -20 μA	4.4	4.5	-	4.4	-	4.4	-	V
		I _O = -4.0 mA	3.98	4.32	-	3.84	-	3.7	-	V
V _{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
outpu	output voltage	I _O = 20 μA	-	0	0.1	-	0.1	-	0.1	٧
		I _O = 4.0 mA	-	0.15	0.26	-	0.33	-	0.4	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μA
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	8.0	-	80.0	-	160.0	μA
Δl _{CC}	additional supply current	per input pin; $V_I = V_{CC} - 2.1 \text{ V}$; other inputs at V_{CC} or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V; $I_O = 0 \text{ A}$								
		pin MR	-	95	342	-	427.5	-	465.5	μΑ
		pin CP	-	110	396	-	495	-	539	μΑ
		pin CEP and Dn	-	25	90	-	112.5	-	122.5	μΑ
		pin CET	-	75	270	-	337.5	-	367.5	μΑ
		pin PE	-	30	108	-	135	-	147	μΑ
Cı	input capacitance		-	3.5	-	-	-	-	-	pF

10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); C_L = 50 pF unless otherwise specified; for test circuit see Fig. 14.

Symbol	Parameter	Conditions		25 °C		-40 °C to	+85 °C	-40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	1
74HC16	3-Q100				1			-		
t _{pd}	propagation	CP to Qn; see Fig. 9 [1]							
	delay	V _{CC} = 2.0 V	-	55	185	-	230	-	280	ns
		V _{CC} = 4.5 V	-	20	37	-	46	-	56	ns
		V _{CC} = 5.0 V; C _L = 15 pF	-	17	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	16	31	-	39	-	48	ns
		CP to TC; see Fig. 9								
		V _{CC} = 2.0 V	-	69	215	-	270	-	320	ns
		V _{CC} = 4.5 V	-	25	43	-	54	-	65	ns
		V _{CC} = 5.0 V; C _L = 15 pF	-	21	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	20	37	-	46	-	55	ns
		CET to TC; see Fig. 10								
		V _{CC} = 2.0 V	-	36	120	-	150	-	180	ns
		V _{CC} = 4.5 V	-	13	24	-	30	-	36	ns
		V _{CC} = 5.0 V; C _L = 15 pF	-	11	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	10	20	-	26	-	31	ns
t _t	transition	see <u>Fig. 9</u> and <u>Fig. 10</u> [2]							
	time	V _{CC} = 2.0 V	-	19	75	-	95	-	110	ns
		V _{CC} = 4.5 V	-	7	15	-	19	-	22	ns
		V _{CC} = 6.0 V	-	6	13	-	16	-	19	ns
t _W	pulse width	CP; HIGH or LOW; see Fig. 9								
		V _{CC} = 2.0 V	80	17	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	6	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	5	-	17	-	20	-	ns
t _{su}	set-up time	MR, Dn to CP; see Fig. 11 and Fig. 12								
		V _{CC} = 2.0 V	80	17	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	6	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	5	-	17	-	20	-	ns
		PE to CP; see Fig. 11								
		V _{CC} = 2.0 V	80	22	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	8	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	6	-	17	-	20	-	ns
		CEP, CET to CP; see Fig. 13								
		V _{CC} = 2.0 V	175	58	-	220	-	265	-	ns
		V _{CC} = 4.5 V	35	21	-	44	-	53	-	ns
		V _{CC} = 6.0 V	30	17	-	37	-	45	-	ns

Symbol	Parameter	Conditions		25 °C		-40 °C to	-85 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
t _h	hold time	Dn, PE, CEP, CET, MR to CP; see Fig. 11, Fig. 12 and Fig. 13								
		V _{CC} = 2.0 V	0	-14	-	0	-	0	-	ns
		V _{CC} = 4.5 V	0	-5	-	0	-	0	-	ns
		V _{CC} = 6.0 V	0	-4	-	0		0	-	ns
f _{max}	maximum	CP; see Fig. 9								
	frequency	V _{CC} = 2.0 V	5	15	-	4	-	4	-	MHz
		V _{CC} = 4.5 V	27	46	-	22	-	18	-	MHz
		V _{CC} = 5.0 V; C _L = 15 pF	-	51	-	-	-	-	-	MHz
		V _{CC} = 6.0 V	32	55	-	26	-	21	-	MHz
C _{PD}	power dissipation capacitance	V_I = GND to V_{CC} ; V_{CC} = 5 V; [3] f_i = 1 MHz	-	33	-	-	-	-	-	pF
74HCT1	63-Q100									
t _{pd}	propagation	CP to Qn; see Fig. 9 [1]								
	delay	V _{CC} = 4.5 V	-	23	39	-	49	-	59	ns
		V _{CC} = 5.0 V; C _L = 15 pF	-	20	-	-	-	-	-	ns
		CP to TC; see Fig. 9								
		V _{CC} = 4.5 V	-	29	49	-	61	-	74	ns
		V _{CC} = 5.0 V; C _L = 15 pF	-	25	-	-	-	-	-	ns
		CET to TC; see Fig. 10								
		V _{CC} = 4.5 V	-	17	32	-	44	-	48	ns
		V _{CC} = 5.0 V; C _L = 15 pF	-	14	-	-	-	-	-	ns
t _t	transition	see <u>Fig. 9</u> and <u>Fig. 10</u> [2]								
	time	V _{CC} = 4.5 V	-	7	15	-	19	-	22	ns
t _W	pulse width	CP; HIGH or LOW; see Fig. 9								
		V _{CC} = 4.5 V	20	6	-	25	-	30	-	ns
t _{su}	set-up time	MR, Dn to CP; see Fig. 11 and Fig. 12								
		V _{CC} = 4.5 V	20	9	-	25	-	30	-	ns
		PE to CP; see Fig. 11								
		V _{CC} = 4.5 V	20	11	-	25	-	30	-	ns
		CEP, CET to CP; see Fig. 13								
		V _{CC} = 4.5 V	40	24	-	50	-	60	-	ns
t _h	hold time	Dn, PE, CEP, CET, MR to CP; see Fig. 11, Fig. 12 and Fig. 13								
		V _{CC} = 4.5 V	0	-5	-	0	-	0	-	ns
f _{max}	maximum	CP; see Fig. 9								
	frequency	V _{CC} = 4.5 V	26	45	-	21	-	17	-	MHz
		V _{CC} = 5.0 V; C _L = 15 pF	-	50	-	-	-	-	-	MHz

Symbol	Parameter	Conditions	25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit	
			Min	Тур	Max	Min	Max	Min	Max	
C _{PD}	power dissipation capacitance	$V_{I} = GND \text{ to } V_{CC} - 1.5 \text{ V};$ [3] $V_{CC} = 5 \text{ V}; f_{i} = 1 \text{ MHz}$	-	35	-	-	-	-	-	pF

- [1] t_{pd} is the same as t_{PHL} and t_{PLH} .
- [2] t_t is the same as t_{THL} and t_{TLH} .
- [3] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W):

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

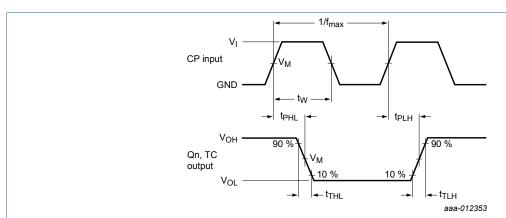
C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_0) = \text{sum of outputs.}$

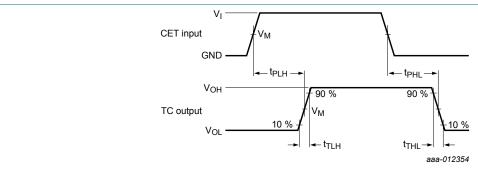
10.1. Waveforms and test circuit



Measurement points are given in Table 8.

Logic levels V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

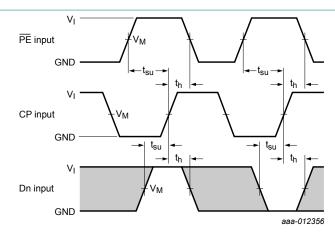
Fig. 9. The clock (CP) to outputs (Qn, TC) propagation delays, pulse width, output transition times and maximum frequency



Measurement points are given in Table 8.

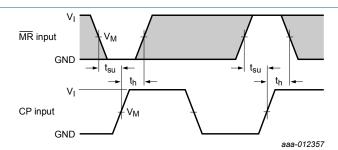
Logic levels V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 10. The count enable carry input (CET) to terminal count output (TC) propagation delays and output transition times



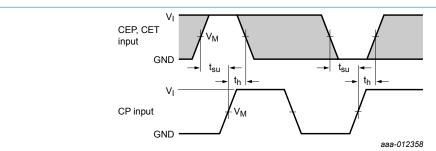
The shaded areas indicate when the input is permitted to change for predictable output performance. Measurement points are given in <u>Table 8</u>.

Fig. 11. The data input (Dn) and parallel enable input (PE) set-up and hold times



The shaded areas indicate when the input is permitted to change for predictable output performance. Measurement points are given in <u>Table 8</u>.

Fig. 12. The master reset (MR) set-up and hold times



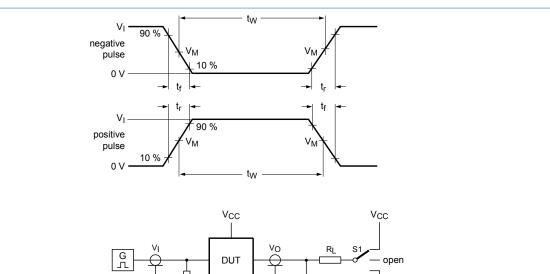
The shaded areas indicate when the input is permitted to change for predictable output performance. Measurement points are given in <u>Table 8</u>.

Fig. 13. The count enable input (CEP) and count enable carry input (CET) set-up and hold times

Table 8. Measurement points

Туре	Input		Output
	V _M	V _I	
74HC163-Q100	0.5 x V _{CC}	GND to V _{CC}	0.5 x V _{CC}
74HCT163-Q100	1.3 V	GND to 3 V	1.3 V

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Test data is given in Table 9.

Test circuit definitions:

 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator

C_L = Load capacitance including jig and probe capacitance

 R_L = Load resistance.

S1 = Test selection switch

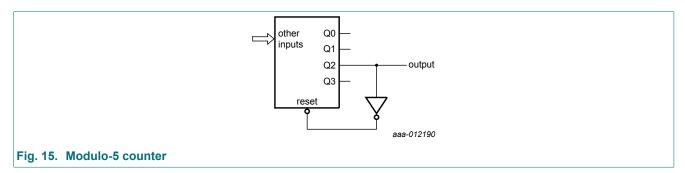
Fig. 14. Test circuit for measuring switching times

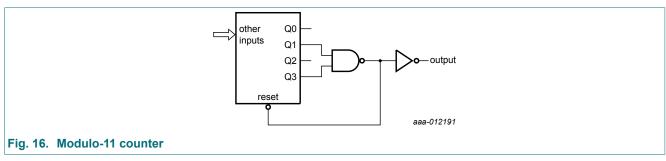
Table 9. Test data

Туре	Input		Load		S1 position
	V _I	t _r , t _f	CL	R _L	t _{PHL} , t _{PLH}
74HC163-Q100	V _{CC}	6 ns	15 pF, 50 pF	1 kΩ	open
74HCT163-Q100	3 V	6 ns	15 pF, 50 pF	1 kΩ	open

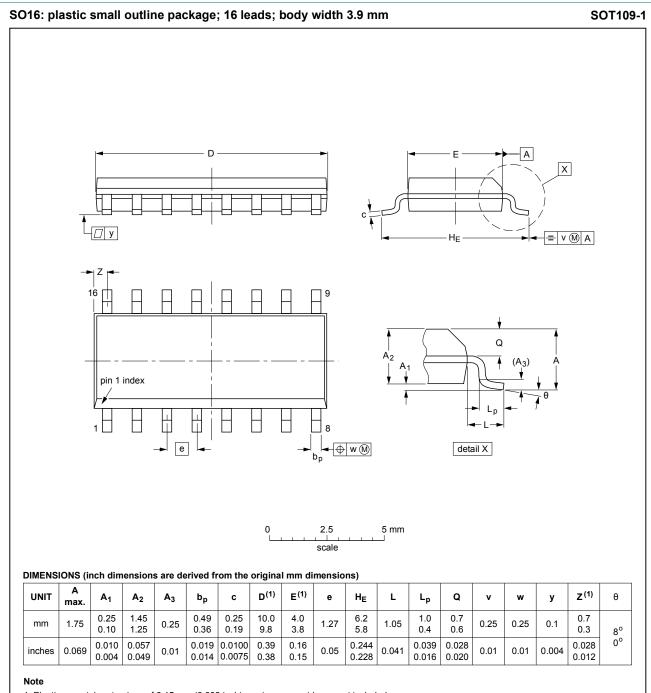
11. Application information

The 74HC163-Q100; 74HCT63-Q100 facilitate designing counters of any modulus with minimal external logic. The output is glitch-free due to the synchronous reset.





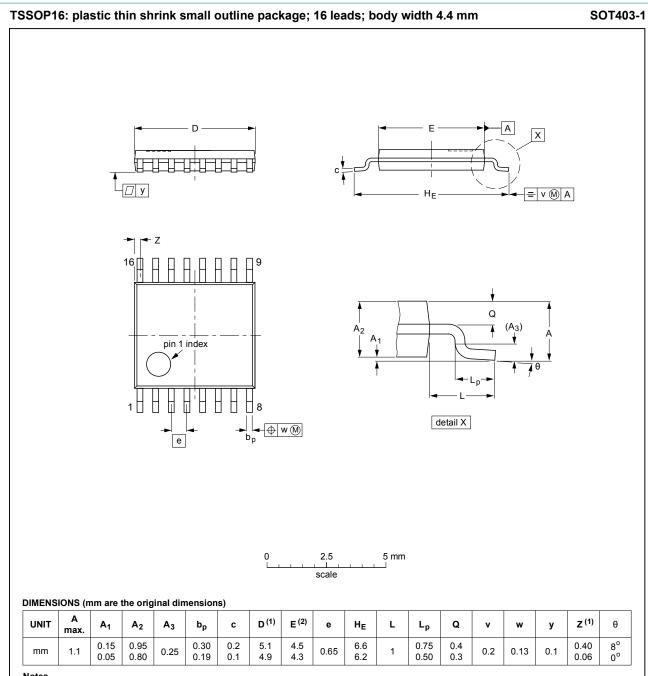
12. Package outline



1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE	REFERENCES			EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT109-1	076E07	MS-012				99-12-27 03-02-19

Fig. 17. Package outline SOT109-1 (SO16)



Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE	REFERENCES				EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT403-1		MO-153				99-12-27 03-02-18

Fig. 18. Package outline SOT403-1 (TSSOP16)

13. Abbreviations

Table 10. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
MIL	Military
TTL	Transistor-Transistor Logic

14. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT163_Q100 v.2	20181012	Product data sheet	-	74HC_HCT163_Q100 v.1
Modifications:	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Typo corrected for pin name Q0: Fig. 5 and Fig. 6. 			
74HC_HCT163_Q100 v.1	20140619	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at https://www.nexperia.com.

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